

Ordering number : ENN6996

P-Channel Silicon MOSFET

CPH3307



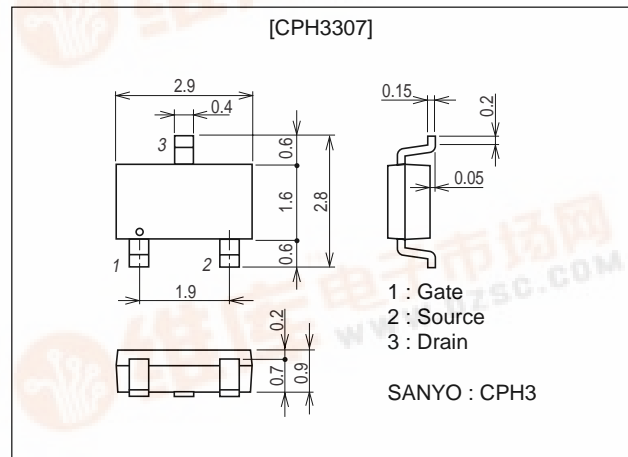
Ultrahigh-Speed Switching Applications

Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 2.5V drive.

Package Dimensions

unit : mm
2152A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-20	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	I _D		-3	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-12	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (900mm ² X0.8mm)	1.2	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =-1mA, V _{GS} =0	-20			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0			-1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-0.4		-1.4	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-1.5A	3.5	5		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-1.5A, V _{GS} =-4V		70	90	mΩ
	R _{DS(on)2}	I _D =-1A, V _{GS} =-2.5V		95	130	mΩ

Marking : JG

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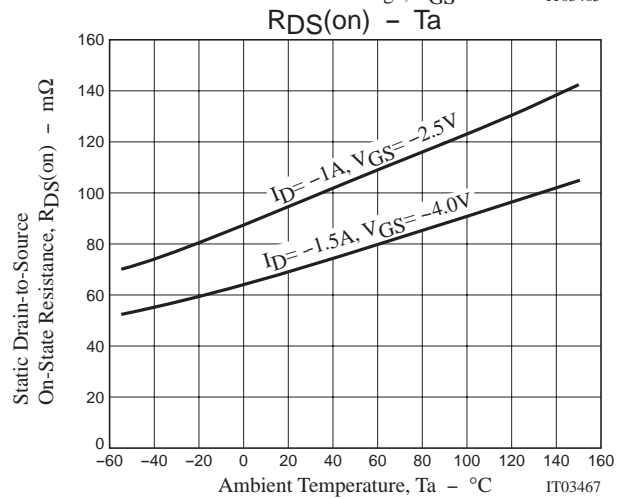
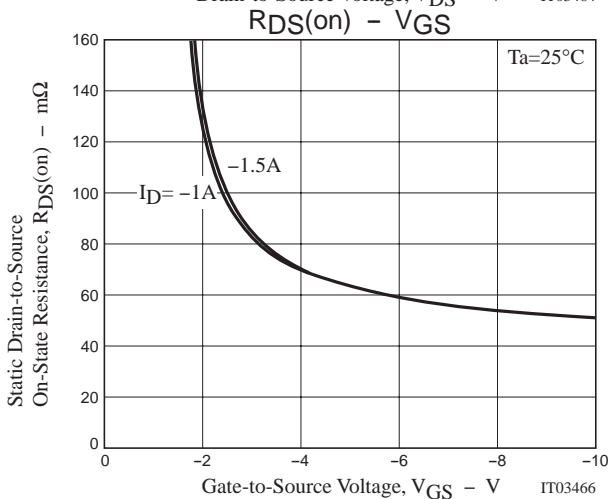
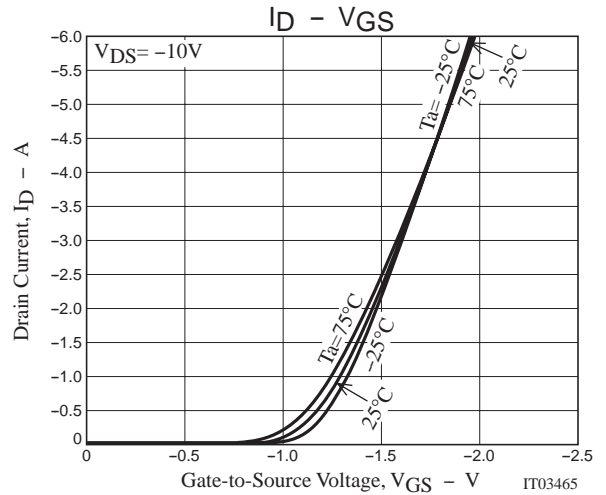
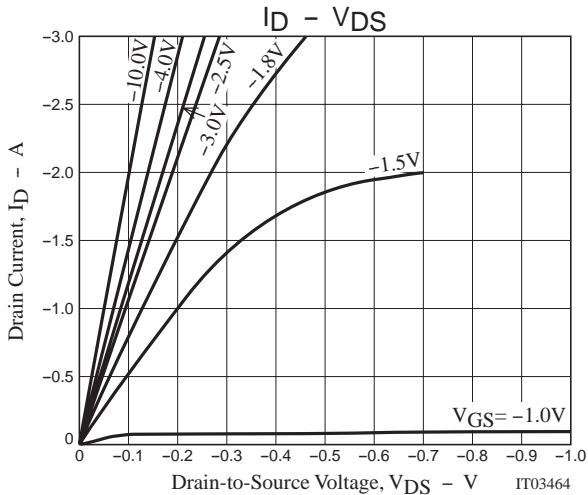
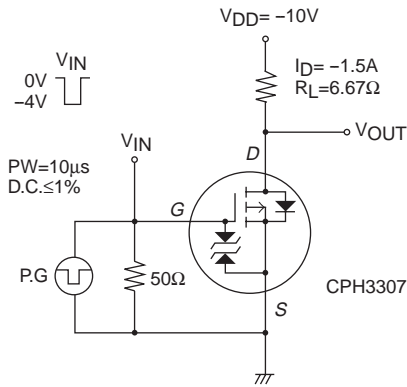


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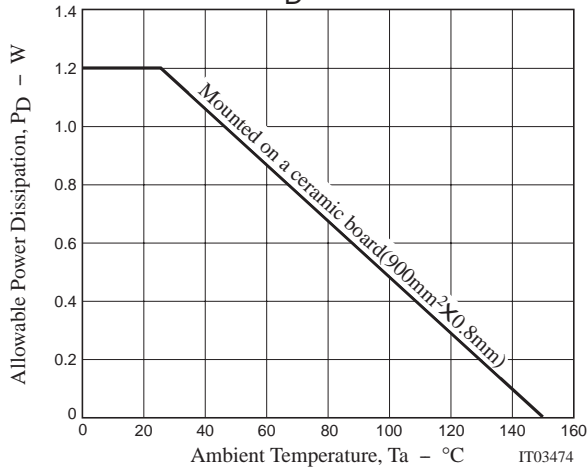
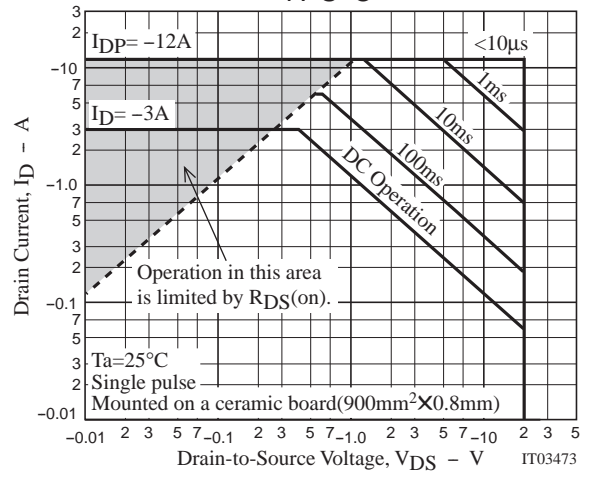
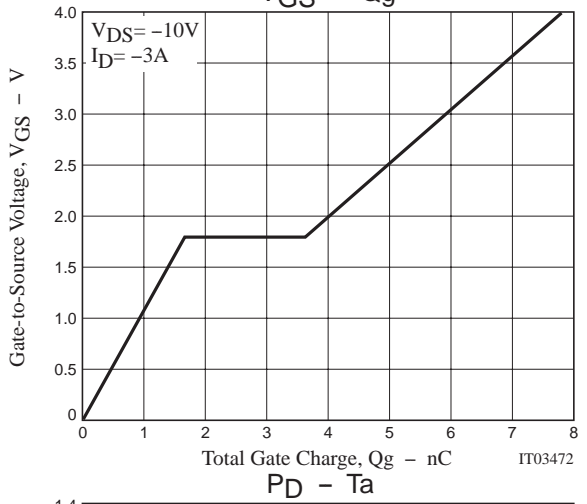
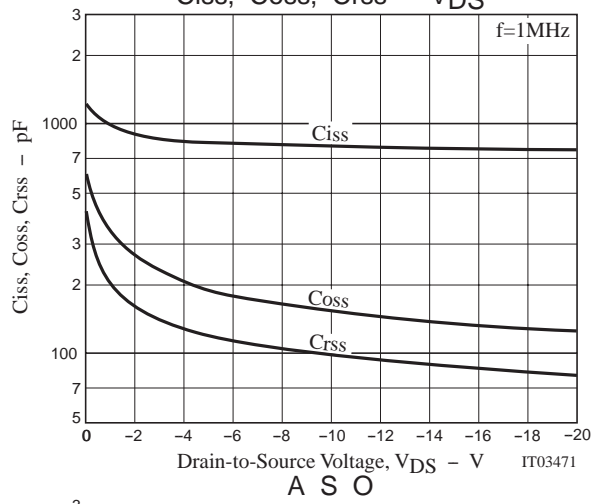
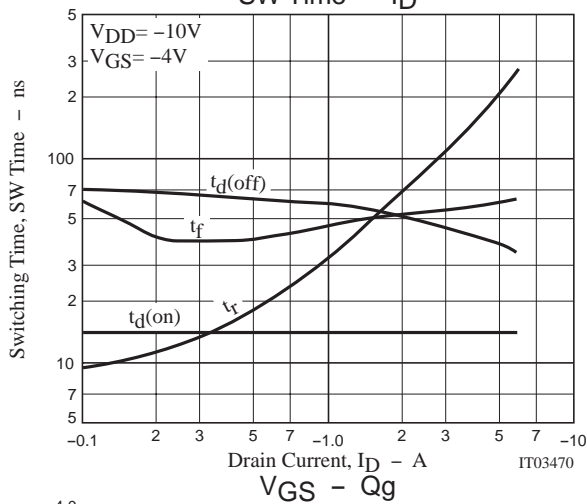
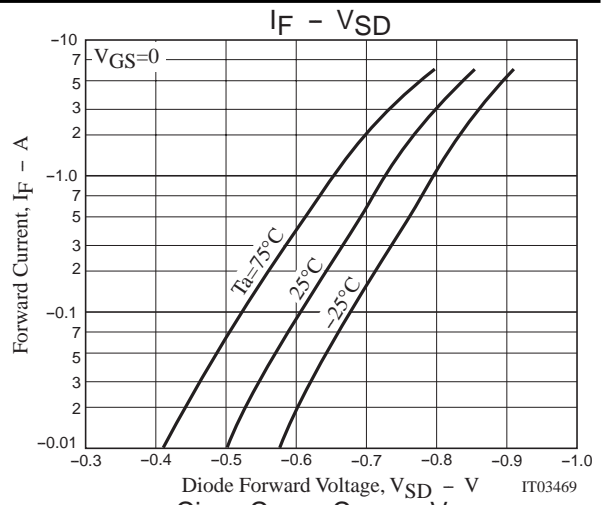
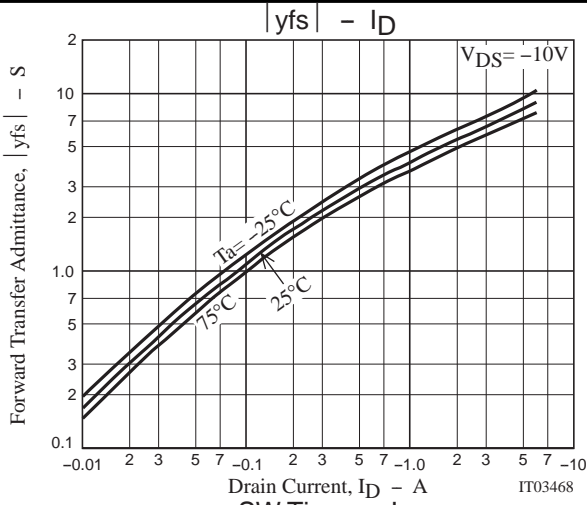
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	$V_{DS}=-10V, f=1MHz$		800		pF
Output Capacitance	Coss	$V_{DS}=-10V, f=1MHz$		160		pF
Reverse Transfer Capacitance	Crss	$V_{DS}=-10V, f=1MHz$		100		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit		14		ns
Rise Time	t_r	See specified Test Circuit		50		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit		56		ns
Fall Time	t_f	See specified Test Circuit		51		ns
Total Gate Charge	Qg	$V_{DS}=-10V, V_{GS}=-4V, I_D=-3A$		7.8		nC
Gate-to-Source Charge	Qgs	$V_{DS}=-10V, V_{GS}=-4V, I_D=-3A$		1.7		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS}=-10V, V_{GS}=-4V, I_D=-3A$		1.9		nC
Diode Forward Voltage	VSD	$I_S=-3A, V_{GS}=0$		-0.8	-1.5	V

Switching Time Test Circuit



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